

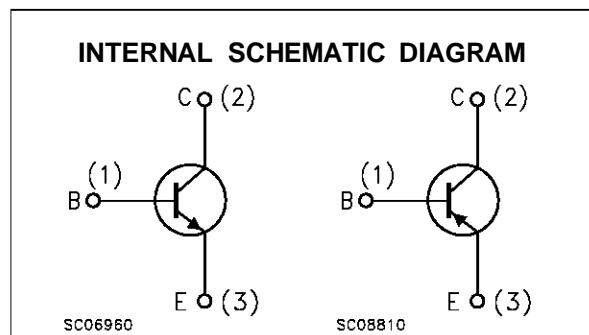
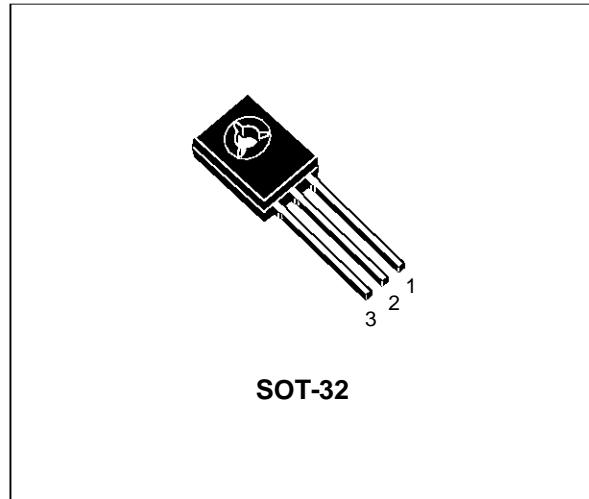
## COMPLEMENTARY SILICON POWER TRANSISTORS

- SGS-THOMSON PREFERRED SALESTYPES

### DESCRIPTION

The BD235 and BD237 are silicon epitaxial-base NPN power transistors in Jedec SOT-32 plastic package intended for use in medium power linear and switching applications.

The complementary PNP types are BD236 and BD238 respectively.



### ABSOLUTE MAXIMUM RATINGS

| Symbol    | Parameter   | Value |            | Unit             |
|-----------|---|-------|------------|------------------|
|           |   | NPN   | BD235      |                  |
|           |   | PNP   | BD236      |                  |
| $V_{CBO}$ | Collector-Base Voltage ( $I_E = 0$ )                  |       | 60         | V                |
| $V_{CER}$ | Collector-Base Voltage ( $R_{BE} = 1\text{K}\Omega$ ) |       | 60         | V                |
| $V_{CEO}$ | Collector-Emitter Voltage ( $I_B = 0$ )               |       | 60         | V                |
| $V_{EBO}$ | Emitter-Base Voltage ( $I_C = 0$ )                    |       | 5          | V                |
| $I_C$     | Collector Current                                     |       | 2          | A                |
| $I_{CM}$  | Collector Peak Current                                |       | 6          | A                |
| $P_{tot}$ | Total Dissipation at $T_c = 25^\circ\text{C}$         |       | 25         | W                |
| $T_{stg}$ | Storage Temperature                                   |       | -65 to 150 | $^\circ\text{C}$ |
| $T_j$     | Max. Operating Junction Temperature                   |       | 150        | $^\circ\text{C}$ |

For PNP types voltage and current values are negative.

## BD235/BD236/BD237/BD238

### THERMAL DATA

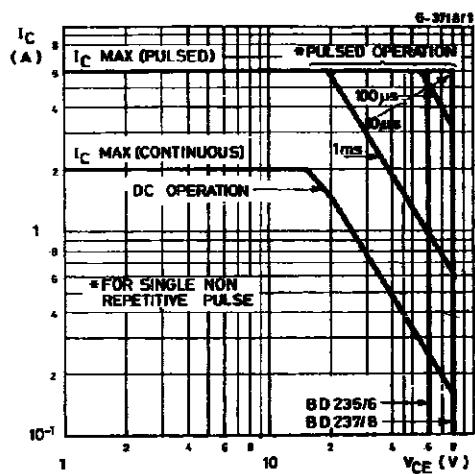
|                |                                  |     |   |                      |
|----------------|----------------------------------|-----|---|----------------------|
| $R_{thj-case}$ | Thermal Resistance Junction-case | Max | 5 | $^{\circ}\text{C/W}$ |
|----------------|----------------------------------|-----|---|----------------------|

### ELECTRICAL CHARACTERISTICS ( $T_{case} = 25 \text{ }^{\circ}\text{C}$ unless otherwise specified)

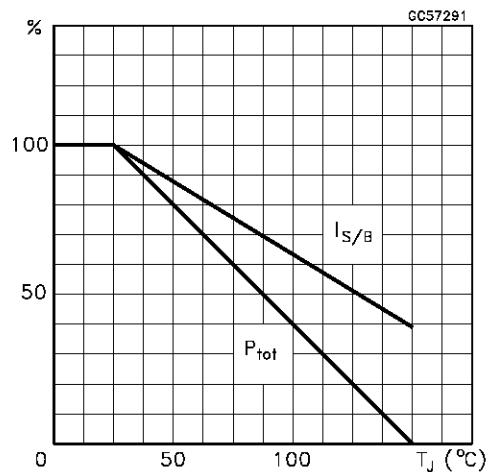
| Symbol             | Parameter                               | Test Conditions   | Min.     | Typ. | Max.     | Unit     |
|--------------------|---|---|----------|------|----------|----------|
| $I_{CBO}$          | Collector Cut-off Current ( $I_E = 0$ ) | $V_{CE} = \text{rated } V_{CEO}$<br>$V_{CE} = \text{rated } V_{CEO} \quad T_c = 150 \text{ }^{\circ}\text{C}$ |          |      | 0.1<br>2 | mA<br>mA |
| $I_{EBO}$          | Emitter Cut-off Current ( $I_C = 0$ )   | $V_{EB} = 5 \text{ V}$  |          |      | 1        | mA       |
| $V_{CEO(sus)*}$    | Collector-Emitter Sustaining Voltage    | $I_C = 100 \text{ mA}$<br>for BD235/BD236<br>for BD237/BD238  | 60<br>80 |      |          | V<br>V   |
| $V_{CE(sat)*}$     | Collector-Emitter Saturation Voltage    | $I_C = 1 \text{ A} \quad I_B = 0.1 \text{ A}$   |          |      | 0.6      | V        |
| $V_{BE*}$          | Base-Emitter Voltage                    | $I_C = 1 \text{ A} \quad V_{CE} = 2 \text{ V}$  |          |      | 1.3      | V        |
| $h_{FE*}$          | DC Current Gain                         | $I_C = 150 \text{ mA} \quad V_{CE} = 2 \text{ V}$<br>$I_C = 1 \text{ A} \quad V_{CE} = 2 \text{ V}$           | 40<br>25 |      |          |          |
| $f_T$              | Transition frequency                    | $I_C = 250 \text{ mA} \quad V_{CE} = 10 \text{ V}$  | 3        |      |          | MHz      |
| $h_{FE1}/h_{FE2*}$ | Matched Pairs                           | $I_C = 150 \text{ mA} \quad V_{CE} = 2 \text{ V}$   |          | 1.6  |          |          |

\* Pulsed: Pulse duration = 300  $\mu\text{s}$ , duty cycle 1.5 %

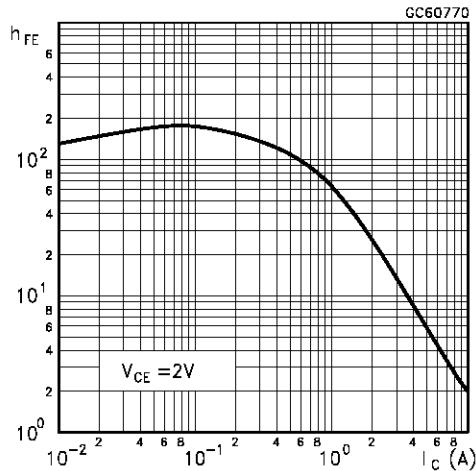
Safe Operating Area



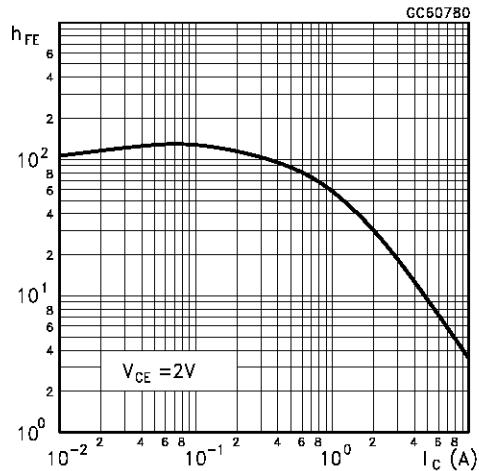
Derating Curves



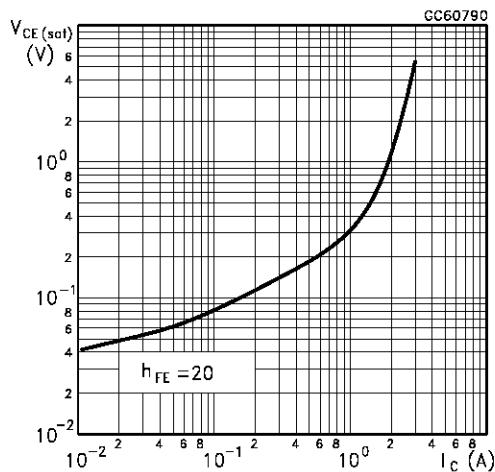
DC Current Gain (NPN type)



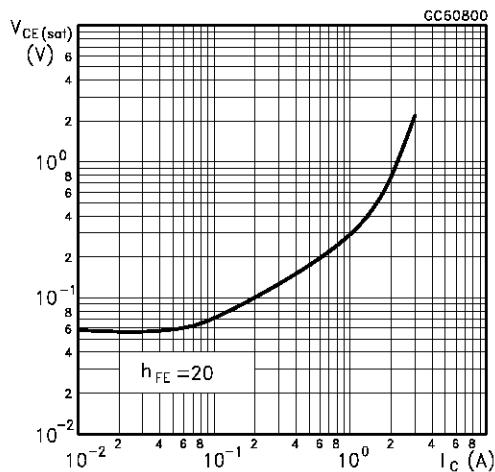
DC Current Gain (PNP type)



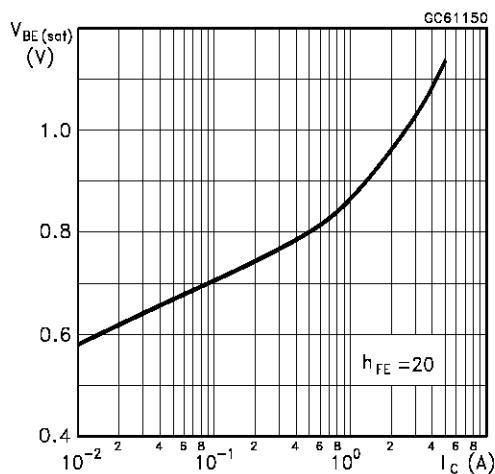
Collector-Emitter Saturation Voltage (NPN type)



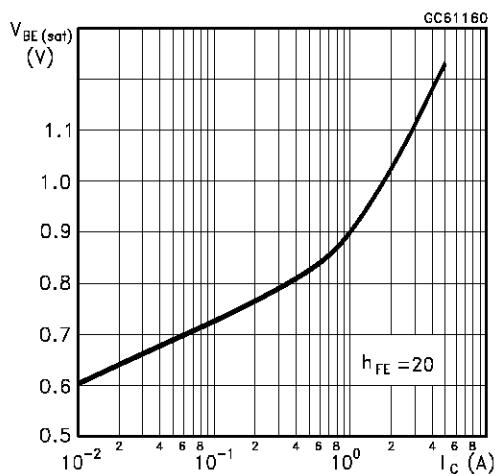
Collector-Emitter Saturation Voltage (PNP type)



Base-Emitter Saturation Voltage (NPN type)

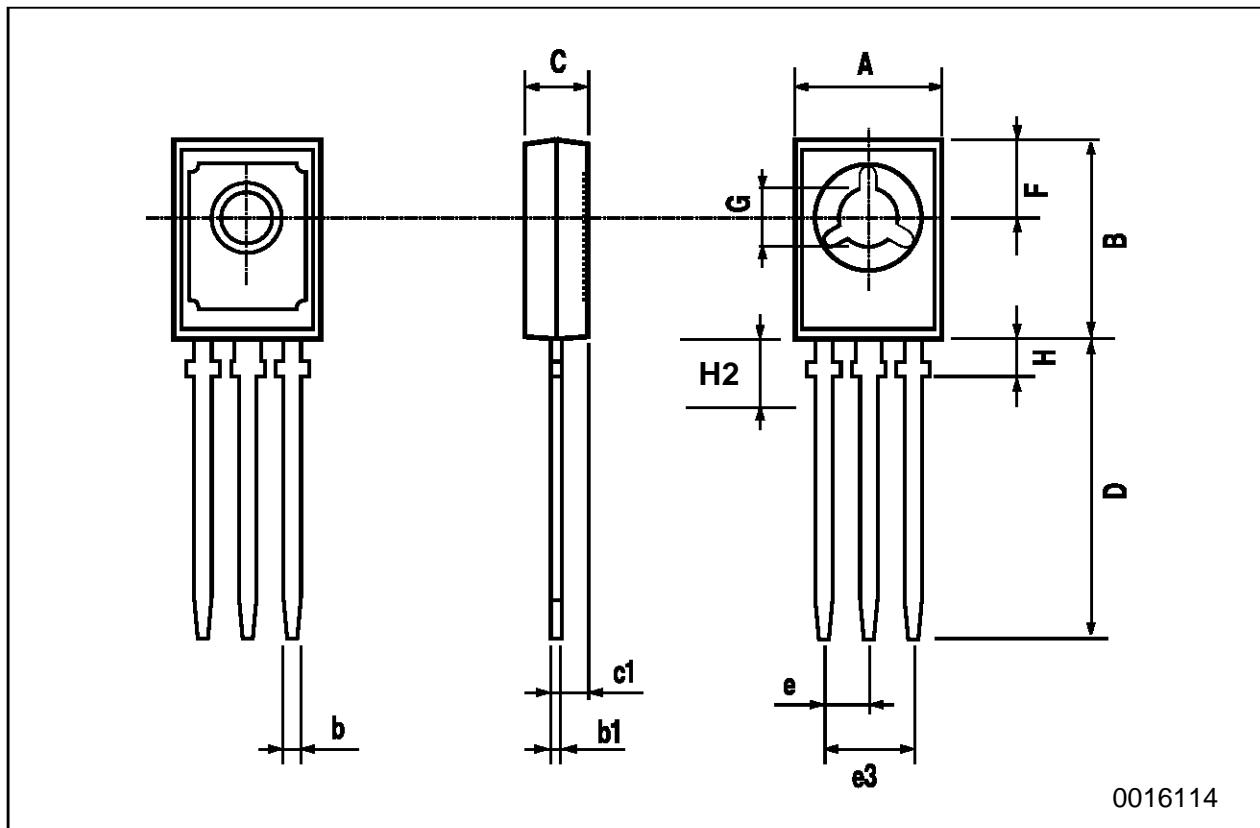


Collector-Base Capacitance (PNP type)



**SOT-32 (TO-126) MECHANICAL DATA**

| DIM. | mm   |      |      | inch  |       |       |
|------|------|------|------|-------|-------|-------|
|      | MIN. | TYP. | MAX. | MIN.  | TYP.  | MAX.  |
| A    | 7.4  |      | 7.8  | 0.291 |       | 0.307 |
| B    | 10.5 |      | 10.8 | 0.413 |       | 0.445 |
| b    | 0.7  |      | 0.9  | 0.028 |       | 0.035 |
| b1   | 0.49 |      | 0.75 | 0.019 |       | 0.030 |
| C    | 2.4  |      | 2.7  | 0.040 |       | 0.106 |
| c1   | 1.0  |      | 1.3  | 0.039 |       | 0.050 |
| D    | 15.4 |      | 16.0 | 0.606 |       | 0.629 |
| e    |      | 2.2  |      |       | 0.087 |       |
| e3   | 4.15 |      | 4.65 | 0.163 |       | 0.183 |
| F    |      | 3.8  |      |       | 0.150 |       |
| G    | 3    |      | 3.2  | 0.118 |       | 0.126 |
| H    |      |      | 2.54 |       |       | 0.100 |
| H2   |      | 2.15 |      |       | 0.084 |       |



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